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Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







EFC4626R



N-Channel Power MOSFET 24V, 5A, 46.2mΩ, Dual EFCP

http://onsemi.com

Features

• 2.5V drive

- Common-drain type
- Protection diode in
- 2KV ESD HBM
- Halogen free compliance

Applications

• Lithium-ion battery charging and discharging switch

Specifications

Absolute Maximum Ratings at Ta = 25°C

| Parameter | Symbol | Conditions | Value | Unit |
|--------------------------|------------------|--|--------------|------|
| Source to Source Voltage | V _{SSS} | | 24 | V |
| Gate to Source Voltage | V _{GSS} | | ±10 | V |
| Source Current (DC) | IS | | 5 | Α |
| Source Current (Pulse) | I _{SP} | PW≤10μs, duty cycle≤1% | 60 | Α |
| Total Dissipation | PT | When mounted on ceramic substrate (5000mm ² ×0.8mm) | 1.4 | W |
| Junction Temperature | Тј | | 150 | °C |
| Storage Temperature | Tstg | | - 55 to +150 | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Thermal Resistance Ratings

| Parameter | Symbol | Value | Unit |
|--|-----------------|-------|-------|
| Junction to Ambient | $R_{\theta JA}$ | 84 | °C /W |
| When mounted on ceramic substrate (5000mm ² ×0.8mm) | | | |

Electrical Characteristics at Ta = 25°C

| Parameter | Symbol | Condit | Conditions | | | Unit | |
|------------------------------------|----------------------|---|----------------|-----|-----|------|-------|
| raidillelei | Symbol | Conditions | | min | typ | max | Offic |
| Source to Source Breakdown Voltage | V(BR)SSS | I _S =1mA, V _{GS} =0V | Test Circuit 1 | 24 | | | V |
| Zero-Gate Voltage Source Current | ISSS | V _{SS} =20V, V _{GS} =0V | Test Circuit 1 | | | 1 | μΑ |
| Gate to Source Leakage Current | IGSS | V _{GS} =±8V, V _{SS} =0V | Test Circuit 2 | | | ±1 | μА |
| Gate Threshold Voltage | V _{GS} (th) | V _{SS} =10V, I _S =1mA | Test Circuit 3 | 0.5 | | 1.3 | ٧ |
| Forward Transconductance | gFS . | V _{SS} =10V, I _S =2A | Test Circuit 4 | | 7 | | S |

Continued on next page.

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

EFC4626R

Continued from preceding page.

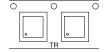
| Parameter | Cumbal | Symbol Conditions Value min typ | | Value | | Unit | |
|---|----------------------|--|------------------|-------|-------|------|----|
| raiailletei | Symbol | | | max | | | |
| | Rss(on)1 | I _S =2A, V _{GS} =4.5V | Test Circuit 5 | 29.2 | 37.5 | 46.2 | mΩ |
| Static Source to Source On-State Resistance | Rss(on)2 | I _S =2A, V _{GS} =4.0V | Test Circuit 5 | 30.8 | 39.5 | 48.6 | mΩ |
| | Rss(on)3 | I _S =2A, V _{GS} =3.8V | Test Circuit 5 | 32.0 | 41.0 | 50.5 | mΩ |
| nesistance | Rss(on)4 | I _S =2A, V _{GS} =3.1V | Test Circuit 5 | 35.5 | 45.5 | 58.3 | mΩ |
| | Rss(on)5 | I _S =2A, V _{GS} =2.5V | Test Circuit 5 | 42.6 | 54.0 | 72.4 | mΩ |
| Turn-ON Delay Time | t _d (on) | V _{SS} =10V, V _{GS} =4.5V, I _S =2A Test Circuit 6 | | | 20 | | ns |
| Rise Time | t _r | | | | 350 | | ns |
| Turn-OFF Delay Time | t _d (off) | | | | 22000 | | ns |
| Fall Time | tf | | | | 38400 | | ns |
| Total Gate Charge | Qg | V _{SS} =10V, V _{GS} =4.5V, I _S =5A | A Test Circuit 7 | | 7.5 | · | nC |
| Forward Source to Source Voltage | V _{F(S-S)} | I _S =2A, V _{GS} =0V | Test Circuit 8 | | 0.81 | 1.2 | V |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

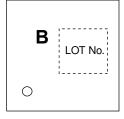
Ordering & Package Information

| Oracing a rackage information | | | | | | | |
|-------------------------------|---------|----------------------|--------------------------------|--|--|--|--|
| Device | Package | Shipping | note | | | | |
| EFC4626R-TR | EFCP | 8,000 pcs. / reel | Pb-Free and Halogen Free | | | | |

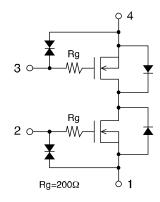
Packing Type: TR



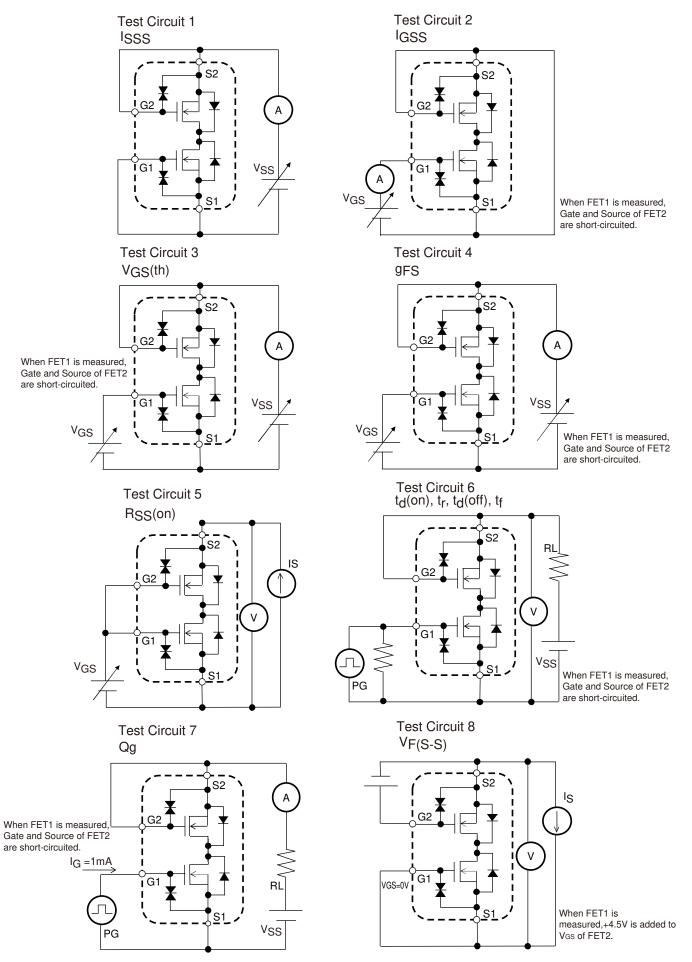
Marking



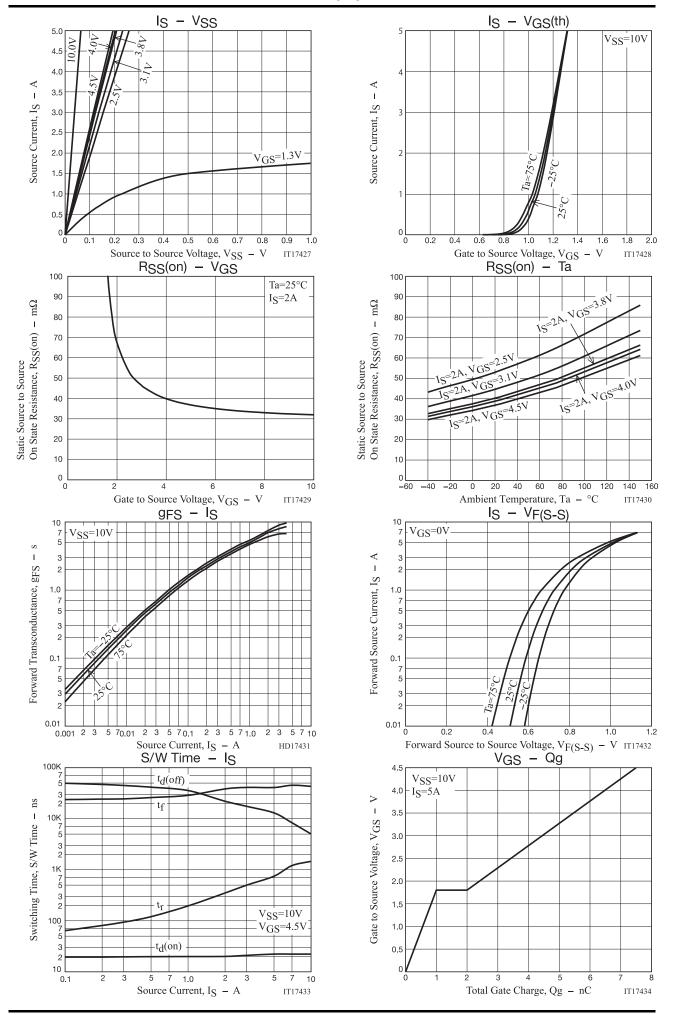
Electrical Connection

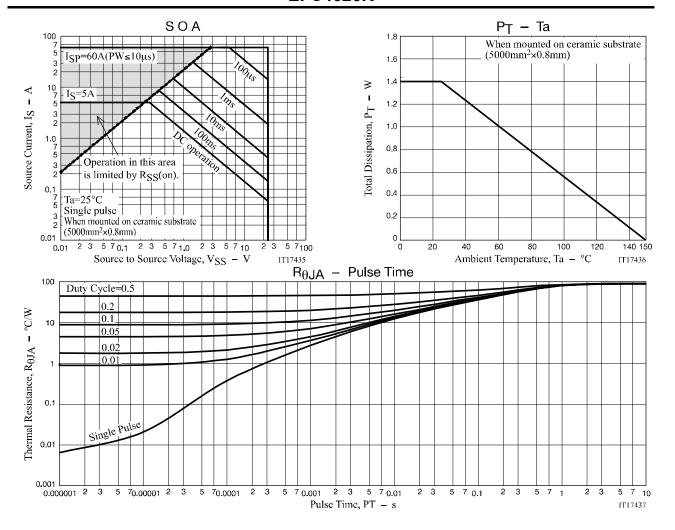


Test circuits are example of measuring FET1 side



When FET2 is measured, the position of FET1 and FET2 is switched.





Package Dimensions

EFC4626R-TR

EFCP1010-4DG-020

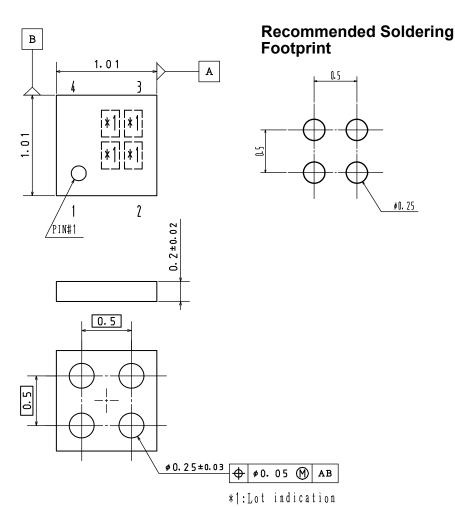
unit: mm

1: Source1

2: Gate1

3: Gate2

4: Source2



Note on usage: Since the EFC4626R is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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